

ROHS EARTH FRIENDLY EARTH FRIENDLY

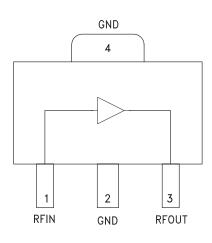
Typical Applications

The HMC453ST89 / HMC453ST89E is ideal for applications requiring a high dynamic range amplifier:

v02.0710

- GSM, GPRS & EDGE
- CDMA & W-CDMA
- CATV/Cable Modem
- Fixed Wireless

Functional Diagram



HMC453ST89 / 453ST89E

InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

Features

Output IP3: +49 dBm 20.5 dB Gain @ 400 MHz 7.5 dB Gain @ 2100 MHz 41% PAE @ +32.5 dBm Pout +26 dBm CDMA2000 Channel Power @ -45 dBc ACP Included in the HMC-DK002 Designer's Kit

General Description

The HMC453ST89 & HMC453ST89E are high dynamic range GaAs InGaP HBT 1.6 Watt MMIC power amplifiers operating from 0.4 to 2.2 GHz and packaged in industry standard SOT89 packages. Utilizing a minimum number of external components and a single +5V supply, the amplifier output IP3 can be optimized to +47 dBm at 0.4 GHz or +49 dBm at 2.1 GHz. The high output IP3 and PAE make the HMC453ST89 & HMC453ST89E ideal power amplifiers for Cellular/ PCS/3G and Fixed Wireless applications.

| Parameter | Min. | Тур. | Max. | Min. | Тур. | Max | Min. | Тур. | Max. | Min. | Тур. | Max. | Min. | Тур. | Max. | Units |
|---|------|----------|------|------|-----------|------|------|-----------|------|------|-----------|------|------|-----------|------|------------|
| Frequency Range | | 400 - 41 | 0 | 4 | 450 - 496 | ; | 8 | 310 - 960 |) | 17 | 710 - 199 | 0 | 20 | 010 - 217 | 70 | MHz |
| Gain | 18 | 20.5 | | 16.5 | 19 | | 12 | 14.5 | | 6 | 8.5 | | 6 | 7.5 | | dB |
| Gain Variation Over Temperature | | 0.012 | 0.02 | | 0.012 | 0.02 | | 0.012 | 0.02 | | 0.012 | 0.02 | | 0.012 | 0.02 | dB / °C |
| Input Return Loss | | 20 | | | 14 | | | 20 | | | 15 | | | 13 | | dB |
| Output Return Loss | | 12 | | | 12 | | | 13 | | | 15 | | | 18 | | dB |
| Output Power for 1dB Compression (P1dB) | 28.5 | 31.5 | | 29 | 32 | | 28.5 | 31.5 | | 29 | 32 | | 29.5 | 32.5 | | dBm |
| Saturated Output Power (Psat) | | 32 | | | 32.25 | | | 31.75 | | | 32.5 | | | 32.75 | | dBm |
| Output Third Order Intercept (IP3) [2] | 44 | 47 | | 45 | 48 | | 44 | 47 | | 46 | 49 | | 46 | 49 | | dBm |
| Noise Figure | | 9 | | | 9 | | | 6.5 | | | 7 | | | 6.5 | | dB |
| Supply Current (Icq) | | 725 | | | 725 | | | 725 | | | 725 | | | 725 | | mA |

[1] Specifications and data reflect HMC453ST89 measured using the respective application circuits for each designated frequency band found herein. Contact the HMC Applications Group for assistance in optimizing performance for your application.

[2] Two-tone input power of 0 dBm per tone, 1 MHz spacing.

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Electrical Specifications, $T_A = +25^{\circ}C$, $Vs = +5V^{[1]}$

HMC453ST89* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

• HMC453ST89 Evaluation Board.

DOCUMENTATION

Application Notes

- AN-1363: Meeting Biasing Requirements of Externally Biased RF/Microwave Amplifiers with Active Bias Controllers
- Broadband Biasing of Amplifiers General Application Note
- MMIC Amplifier Biasing Procedure Application Note
- Thermal Management for Surface Mount Components General Application Note

Data Sheet

HMC453ST89 Data Sheet

TOOLS AND SIMULATIONS \square

• HMC453ST89 S-Parameters

REFERENCE MATERIALS

Quality Documentation

- Package/Assembly Qualification Test Report: 3 Lead Plastic SOT89 Package (QTR: 10002 REV: 02)
- Semiconductor Qualification Test Report: GaAs HBT-B (QTR: 2013-00229)

DESIGN RESOURCES

- HMC453ST89 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC453ST89 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

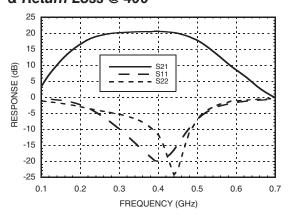
DOCUMENT FEEDBACK

Submit feedback for this data sheet.

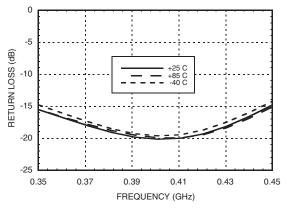




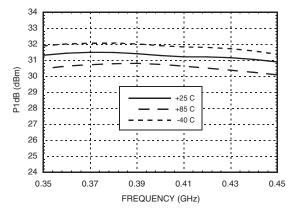
Broadband Gain & Return Loss @ 400



Input Return Loss vs. Temperature @ 400 MHz

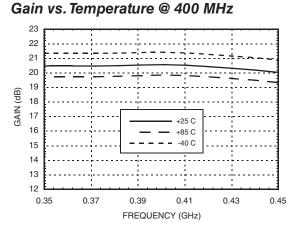


P1dB vs. Temperature @ 400 MHz

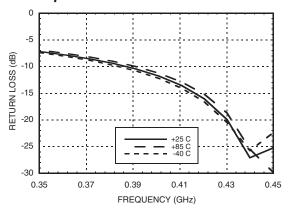


HMC453ST89 / 453ST89E

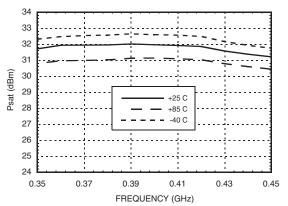
InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



Output Return Loss vs. Temperature @ 400 MHz



Psat vs. Temperature @ 400 MHz



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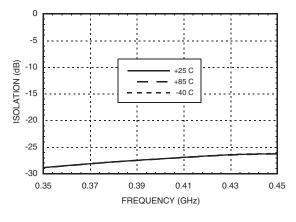




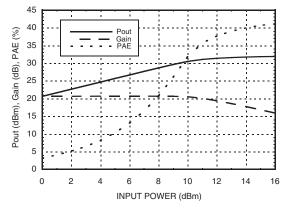
52 50 48 46 44 OIP3 (dBm) 42 +25 C 40 +85 C -40 C 38 36 34 32 30 0.35 0.37 0.39 0.41 0.43 0.45 FREQUENCY (GHz)

Output IP3 vs. Temperature @ 400 MHz

Reverse Isolation vs. Temperature @ 400 MHz

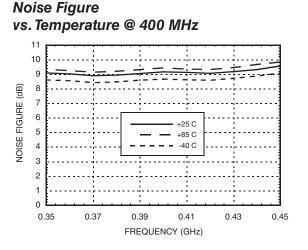


Power Compression @ 400 MHz

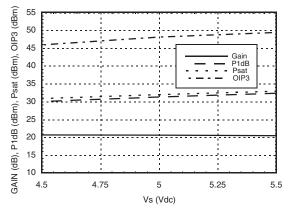


HMC453ST89 / 453ST89E

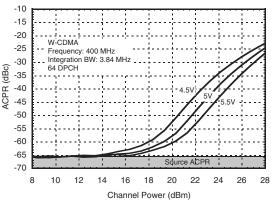
InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



Gain, Power & IP3 vs. Supply Voltage @ 400 MHz



ACPR vs. Supply Voltage @ 400 MHz W-CDMA, 64 DPCH

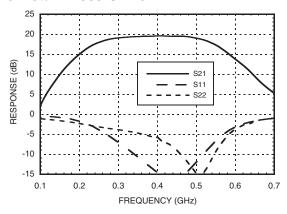


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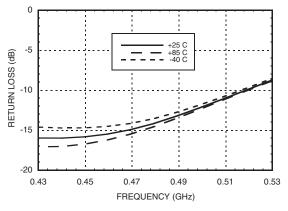




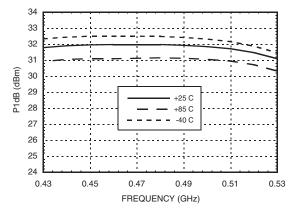
Broadband Gain & Return Loss @ 470 MHz



Input Return Loss vs. Temperature @ 470 MHz

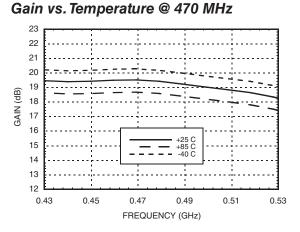


P1dB vs. Temperature @ 470 MHz

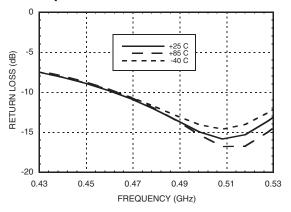


HMC453ST89 / 453ST89E

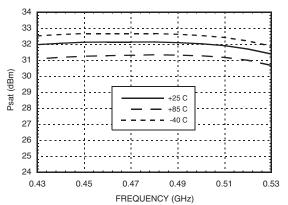
InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



Output Return Loss vs. Temperature @ 470 MHz



Psat vs. Temperature @ 470 MHz

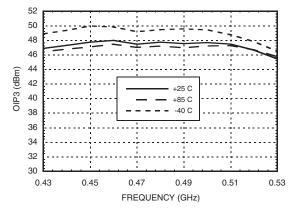


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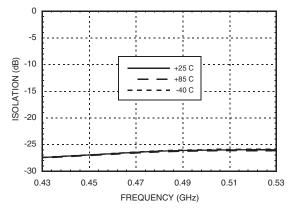




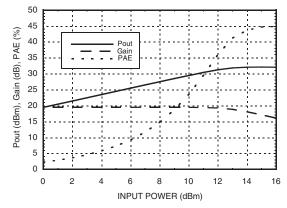
Output IP3 vs. Temperature @ 470 MHz



Reverse Isolation vs. Temperature @ 470 MHz

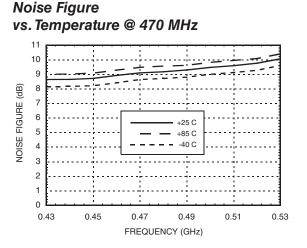


Power Compression @ 470 MHz

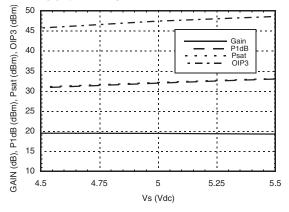


HMC453ST89 / 453ST89E

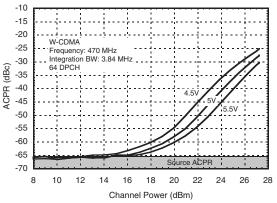
InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



Gain, Power & IP3 vs. Supply Voltage @ 470 MHz



ACPR vs. Supply Voltage @ 470 MHz W-CDMA, 64 DPCH

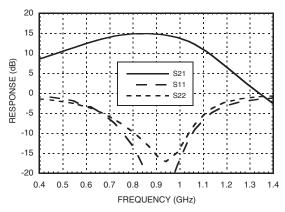


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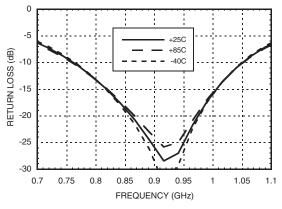




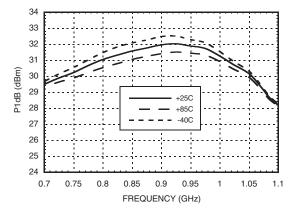
Broadband Gain & Return Loss @ 900 MHz



Input Return Loss vs. Temperature @ 900 MHz

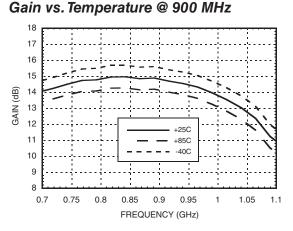


P1dB vs. Temperature @ 900 MHz

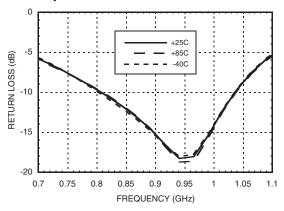


HMC453ST89 / 453ST89E

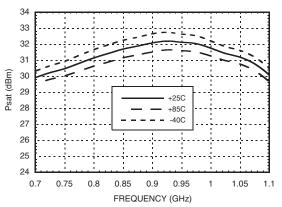
InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



Output Return Loss vs. Temperature @ 900 MHz



Psat vs. Temperature @ 900 MHz

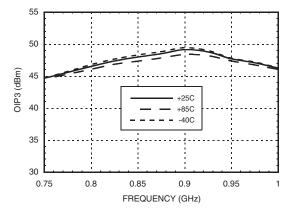


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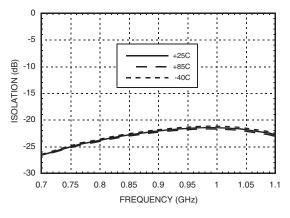




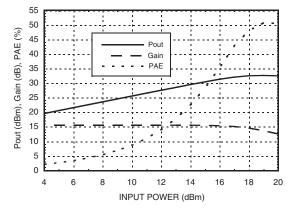
Output IP3 vs. Temperature @ 900 MHz



Reverse Isolation vs. Temperature @ 900 MHz

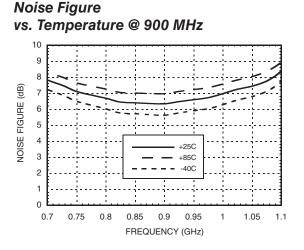


Power Compression @ 900 MHz

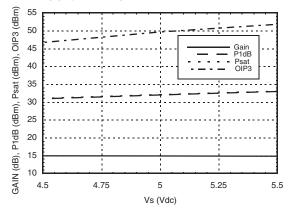


HMC453ST89 / 453ST89E

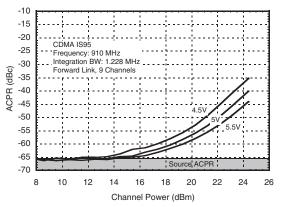
InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



Gain, Power & IP3 vs. Supply Voltage @ 900 MHz



ACPR vs. Supply Voltage @ 910 MHz CDMA IS95, 9 Channels Forward

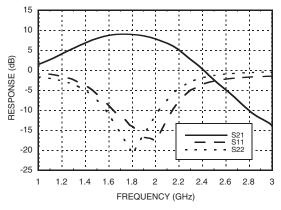


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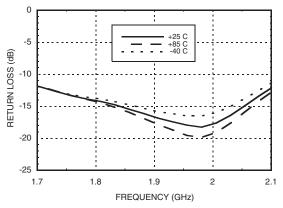




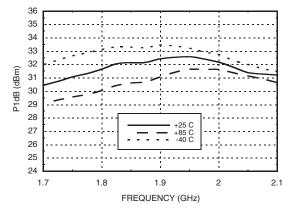
Broadband Gain & Return Loss @ 1900 MHz



Input Return Loss vs. Temperature @ 1900 MHz

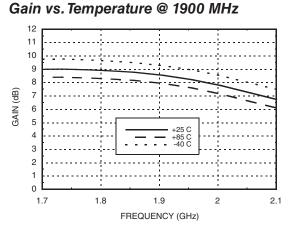


P1dB vs. Temperature @ 1900 MHz

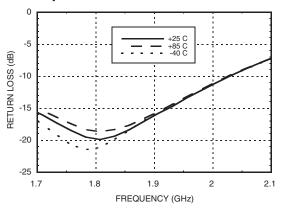


HMC453ST89 / 453ST89E

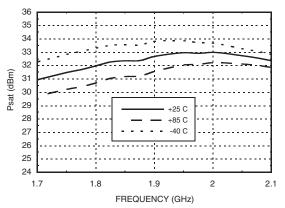
InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



Output Return Loss vs. Temperature @ 1900 MHz



Psat vs. Temperature @ 1900 MHz



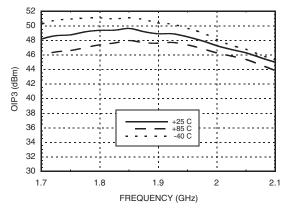
AMPLIFIERS - LINEAR & POWER - SM

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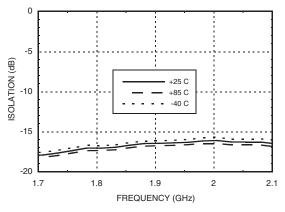




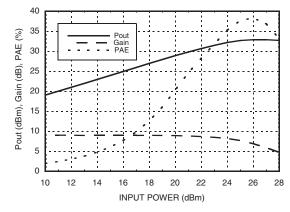
Output IP3 vs. Temperature @ 1900 MHz



Reverse Isolation vs. Temperature @ 1900 MHz

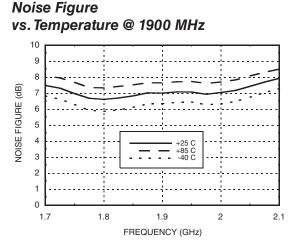


Power Compression @ 1900 MHz

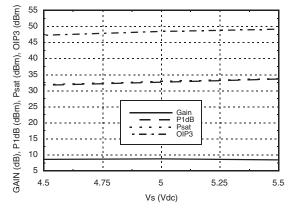


HMC453ST89 / 453ST89E

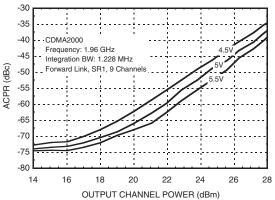
InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



Gain, Power & IP3 vs. Supply Voltage @ 1900 MHz





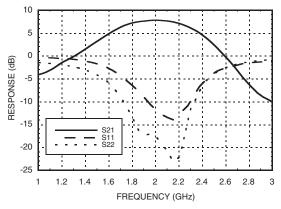


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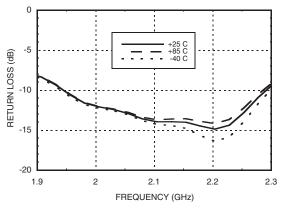




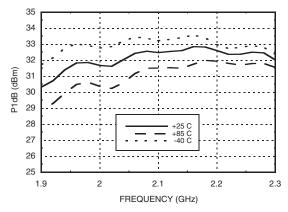
Broadband Gain & Return Loss @ 2100 MHz



Input Return Loss vs. Temperature @ 2100 MHz

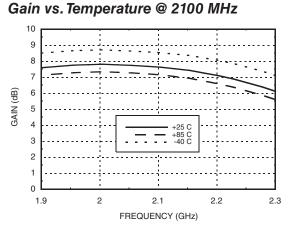


P1dB vs. Temperature @ 2100 MHz

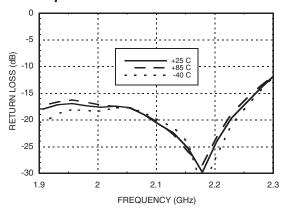


HMC453ST89 / 453ST89E

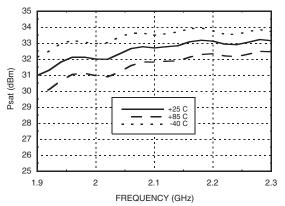
InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



Output Return Loss vs. Temperature @ 2100 MHz



Psat vs. Temperature @ 2100 MHz



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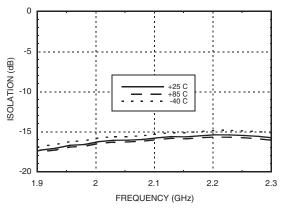




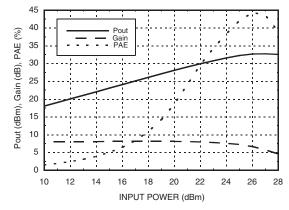
52 50 48 46 44 OIP3 (dBm) 42 +25 C +85 C -40 C 40 38 36 34 32 30 1.9 2 2.1 2.2 2.3 FREQUENCY (GHz)

Output IP3 vs. Temperature @ 2100 MHz

Reverse Isolation vs. Temperature @ 2100 MHz

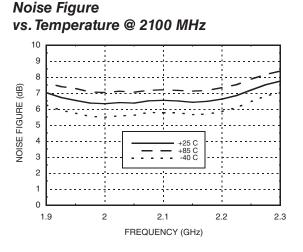


Power Compressions @ 2100 MHz

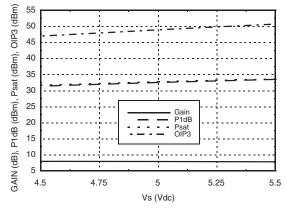


HMC453ST89 / 453ST89E

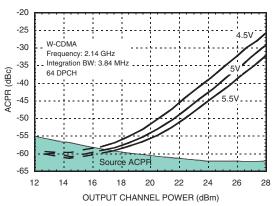
InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



Gain, Power & IP3 vs. Supply Voltage @ 2100 MHz



ACPR vs. Supply Voltage @ 2140 MHz W-CDMA, 64 DPCH

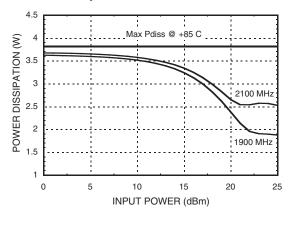


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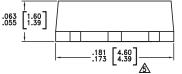


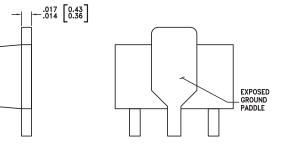
Power Dissipation



Outline Drawing

$:\frac{164}{1.52} \begin{bmatrix} 4.17\\ 1.19\\ 3.86 \end{bmatrix} \xrightarrow{4} \\ \underbrace{HNNN}_{XXXX} \xrightarrow{1000} \begin{bmatrix} 2.59\\ 2.29 \end{bmatrix}} \xrightarrow{1000} \\ \underbrace{1020}_{2.29} \begin{bmatrix} 2.59\\ 0.74 \end{bmatrix} \xrightarrow{1} \\ \underbrace{1020}_{1.19}_{1.19} \\ \underbrace{1020}_{1.19}_{1.19$





NOTES:

1. PACKAGE BODY MATERIAL:

MOLDING COMPOUND MP-180S OR EQUIVALENT.

2. LEAD MATERIAL: Cu w/ Ag SPOT PLATING.

3. LEAD PLATING: 100% MATTE TIN.

4. DIMENSIONS ARE IN INCHES [MILLIMETERS]

A DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE. 7. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

| Part Number | Package Body Material | Lead Finish | MSL Rating | Package Marking ^[3] |
|-------------|--|---------------|---------------------|--------------------------------|
| HMC453ST89 | Low Stress Injection Molded Plastic | Sn/Pb Solder | MSL1 [1] | H453 XXXX |
| HMC453ST89E | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 ^[2] | <u>H453</u> XXXX |

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

Absolute Maximum Ratings

| | - |
|---|----------------|
| Collector Bias Voltage (Vcc) | +6.0 Vdc |
| RF Input Power (RFIN)(Vs +5Vdc) | +32 dBm |
| Junction Temperature | 150 °C |
| Continuous Pdiss (T = 85 °C) (derate 58.5 mW/°C above 85 °C) | 3.8 W |
| Thermal Resistance (junction to ground paddle) | 17.1 °C/W |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -40 to +85 °C |

HMC453ST89 / 453ST89E

InGaP HBT 1.6 WATT POWER

AMPLIFIER, 0.4 - 2.2 GHz



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS



HMC453ST89 / 453ST89E

InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

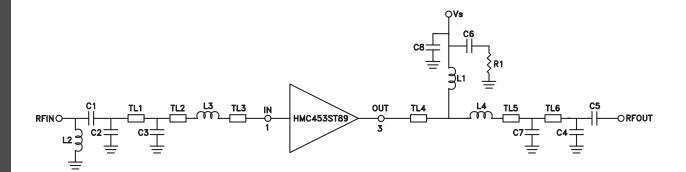


Pin Descriptions

| Pin Number | Function | Description | Interface Schematic |
|------------|----------|---|---------------------|
| 1 | RFIN | This pin is DC coupled. Off chip matching components are required. See Application Circuit herein. | RFINO |
| 3 | RFOUT | RF output and DC Bias input for the amplifier. Off chip matching components are required. See Application Circuit herein. | |
| 2, 4 | GND | These pins & package bottom must be connected to RF/DC ground. | |

400 MHz Application Circuit

This circuit was used to specify the performance for 400-410 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.



| | TL1 | TL2 | TL3 | TL4 | TL5 | TL6 |
|---|--------|--------|--------|--------|------------|--------|
| Impedance | 50 Ohm | 50 Ohm |
| Physical Length | 0.16" | 0.04" | 0.06" | 0.21" | 0.04" | 0.10" |
| Electrical Length | 4° | 1° | 1° | 5° | 1 ° | 2° |
| PCB Material: 10 mil Rogers 4350, Er = 3.48 | | | | | | |

| Recommended C | component Values |
|---------------|------------------|
| C1, C4 | 10 pF |
| C2, C3 | 8.2 pF |
| C5 | 39 pF |
| C6 | 100 pF |
| C7 | 12 pF |
| C8 | 2.2 μF |
| L1 | 47 nH |
| L2 | 40 nH |
| L3 | 4.3 nH |
| L4 | 5.1 nH |
| R1 | 5.1 Ohm |

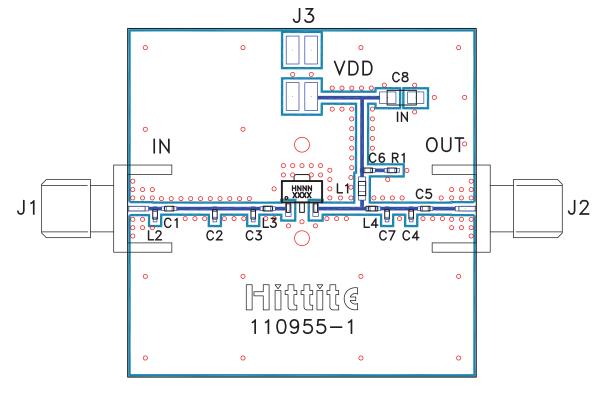
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InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



400 MHz Evaluation PCB



List of Materials for Evaluation PCB 110957-400 [1]

v02.0710

| Item | Description |
|--------------------|--|
| J1 - J2 | PCB Mount SMA Connector |
| J3 | 2 mm DC Header |
| C1, C4 | 10 pF Capacitor, 0402 Pkg. |
| C2, C3 | 8.2 pF Capacitor, 0402 Pkg. |
| C5 | 39 pF Capacitor, 0402 Pkg. |
| C6 | 100 pF Capacitor, 0402 Pkg. |
| C7 | 12 pF Capacitor, 0402 Pkg. |
| C8 | 2.2 µF Capacitor, Tantalum |
| L1 | 47 nH Inductor, 0603 Pkg. |
| L2 | 40 nH Inductor, 0402 Pkg. |
| L3 | 4.3 nH Inductor, 0402 Pkg. |
| L4 | 5.1 nH Inductor, 0402 Pkg. |
| R1 | 5.1 Ohm Resistor, 0402 Pkg. |
| U1 | HMC453ST89 / HMC453ST89E Linear Amp |
| PCB ^[2] | 110955 Evaluation PCB, 10 mils |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350, Er = 3.48

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The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.



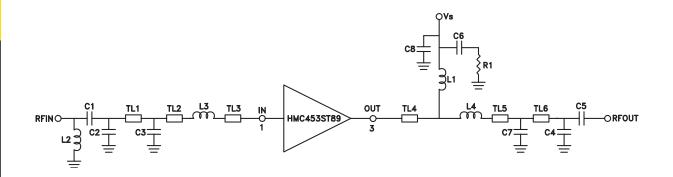
HMC453ST89 / 453ST89E

InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



470 MHz Application Circuit

This circuit was used to specify the performance for 450-496 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.



| | TL1 | TL2 | TL3 | TL4 | TL5 | TL6 |
|--|--------|--------|--------|--------|--------|--------|
| Impedance | 50 Ohm |
| Physical Length | 0.16" | 0.04" | 0.06" | 0.21" | 0.04" | 0.10" |
| Electrical Length 4° 1° 2° 6° 1° 3° | | | | | | |
| PCB Material: 10 mil Bogers 4350 Fr = 3 48 | | | | | | |

| Recommended C | Recommended Component Values | | | | |
|---------------|------------------------------|--|--|--|--|
| C1 | 10 pF | | | | |
| C2, C3 | 6.8 pF | | | | |
| C4 | 12 pF | | | | |
| C5 | 39 pF | | | | |
| C6 | 100 pF | | | | |
| C7 | 5.6 pF | | | | |
| C8 | 2.2 µF | | | | |
| L1 | 47 nH | | | | |
| L2 | 40 nH | | | | |
| L3 | 4.7 nH | | | | |
| L4 | 2.4 nH | | | | |
| R1 | 5.1 Ohm | | | | |

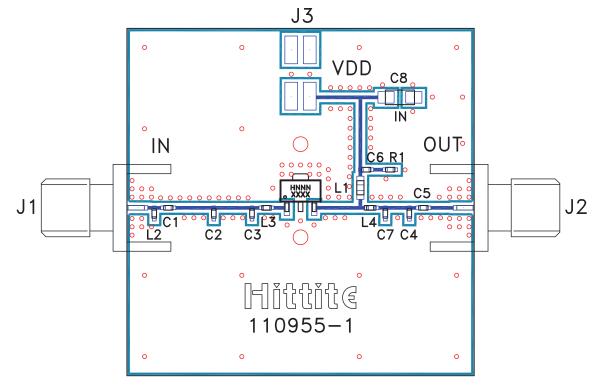
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InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



470 MHz Evaluation PCB



List of Materials for Evaluation PCB 110961-470 [1]

v02.0710

| Item | Description |
|---------|--|
| J1 - J2 | PCB Mount SMA Connector |
| J3 | 2 mm DC Header |
| C1 | 10 pF Capacitor, 0402 Pkg. |
| C2, C3 | 6.8 pF Capacitor, 0402 Pkg. |
| C4 | 12 pF Capacitor, 0402 Pkg. |
| C5 | 39 pF Capacitor, 0402 Pkg. |
| C6 | 100 pF Capacitor, 0402 Pkg. |
| C7 | 5.6 pF Capacitor, 0402 Pkg. |
| C8 | 2.2 µF Capacitor, Tantalum |
| L1 | 47 nH Inductor, 0603 Pkg. |
| L2 | 40 nH Inductor, 0402 Pkg. |
| L3 | 4.7 nH Inductor, 0402 Pkg. |
| L4 | 2.4 nH Inductor, 0402 Pkg. |
| R1 | 5.1 Ohm Resistor, 0402 Pkg. |
| U1 | HMC453ST89 / HMC453ST89E Linear Amp |
| PCB [2] | 110955 Evaluation PCB, 10 mils |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350, Er = 3.48

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

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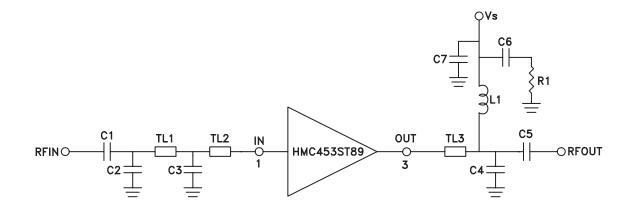
HMC453ST89 / 453ST89E

InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



900 MHz Application Circuit

This circuit was used to specify the performance for 810-960 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.



| | TL1 | TL2 | TL3 | |
|---|--------|--------|--------|--|
| Impedance | 50 Ohm | 50 Ohm | 50 Ohm | |
| Physical Length | 0.25" | 0.08" | 0.31" | |
| Electrical Length 13° 4° 16° | | | | |
| PCB Material: 10 mil Rogers 4350. Er = 3.48 | | | | |

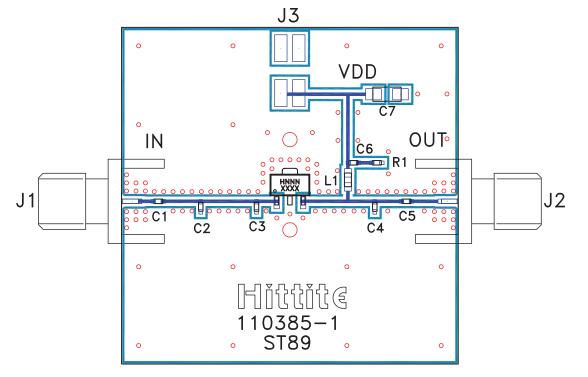
| Recommended C | Recommended Component Values | | | | |
|---------------|------------------------------|--|--|--|--|
| C1 | 5 pF | | | | |
| C2 | 3.3 pF | | | | |
| C3 | 2.7 pF | | | | |
| C4 | 8.2 pF | | | | |
| C5 | 12 pF | | | | |
| C6 | 100 pF | | | | |
| C7 | 2.2 μF | | | | |
| L1 | 15 nH | | | | |
| R1 | 5.1 Ohm | | | | |



InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



900 MHz Evaluation PCB



v02.0710

List of Materials for Evaluation PCB 110387-900 [1]

| Item | Description |
|---------|--|
| J1 - J2 | PCB Mount SMA Connector |
| J3 | 2 mm DC Header |
| C1 | 5 pF Capacitor, 0402 Pkg. |
| C2 | 3.3 pF Capacitor, 0402 Pkg. |
| C3 | 2.7 pF Capacitor, 0402 Pkg. |
| C4 | 8.2 pF Capacitor, 0402 Pkg. |
| C5 | 12 pF Capacitor, 0402 Pkg. |
| C6 | 100 pF Capacitor, 0402 Pkg. |
| C7 | 2.2 µF Capacitor, Tantalum |
| L1 | 15 nH Inductor, 0603 Pkg. |
| R1 | 5.1 Ohm Resistor, 0402 Pkg. |
| U1 | HMC453ST89 / HMC453ST89E Linear Amp |
| PCB [2] | 110385 Evaluation PCB, 10 mils |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350, Er = 3.48

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

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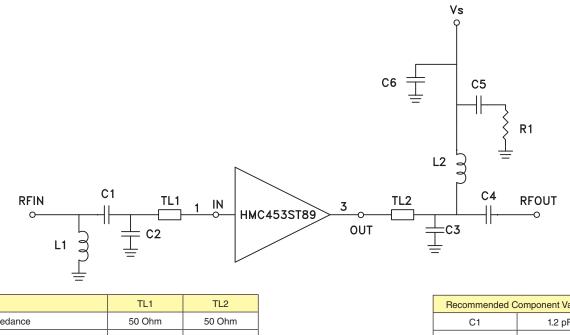
HMC453ST89 / 453ST89E

InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



1900 MHz Application Circuit

This circuit was used to specify the performance for 1710-1990 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.



| | IL1 | IL2 |
|---|--------|--------|
| Impedance | 50 Ohm | 50 Ohm |
| Physical Length | 0.04" | 0.07" |
| Electrical Length | 4° | 8° |
| PCB Material: 10 mil Rogers 4350, Er = 3.48 | | |

| Recommended Component Values | |
|------------------------------|---------|
| C1 | 1.2 pF |
| C2 | 1.5 pF |
| C3 | 3.9 pF |
| C4 | 15 pF |
| C5 | 100 pF |
| C6 | 2.2 μF |
| L1 | 20 nH |
| L2 | 12 nH |
| R1 | 5.1 Ohm |

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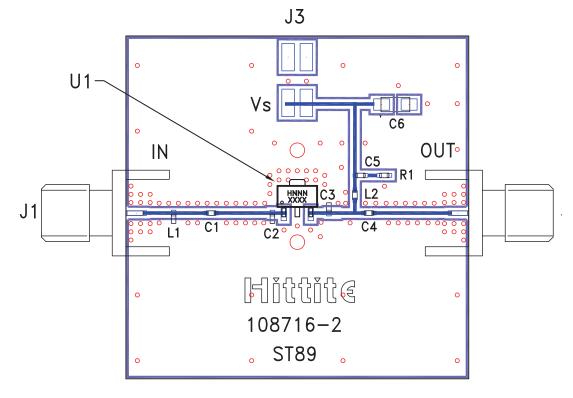


InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



1900 MHz Evaluation PCB

v02.0710



List of Materials for Evaluation PCB 108718-1900 [1]

| Item | Description |
|---------|--|
| J1 - J2 | PCB Mount SMA Connector |
| J3 | 2 mm DC Header |
| C1 | 1.2 pF Capacitor, 0402 Pkg. |
| C2 | 1.5 pF Capacitor, 0402 Pkg. |
| C3 | 3.9 pF Capacitor, 0402 Pkg. |
| C4 | 15 pF Capacitor, 0402 Pkg. |
| C5 | 100 pF Capacitor, 0402 Pkg. |
| C6 | 2.2 µF Capacitor, Tantalum |
| L1 | 20 nH Inductor, 0402 Pkg. |
| L2 | 12 nH Inductor, 0402 Pkg. |
| R1 | 5.1 Ohm Resistor, 0402 Pkg. |
| U1 | HMC453ST89 / HMC453ST89E Linear Amp |
| PCB [2] | 108716 Evaluation PCB, 10 mils |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350, Er = 3.48

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

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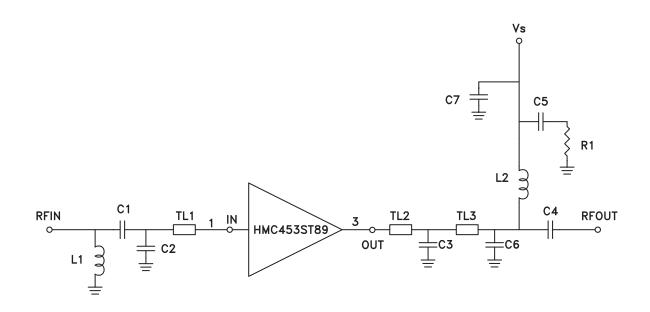
HMC453ST89 / 453ST89E

InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



2100 MHz Application Circuit

This circuit was used to specify the performance for 2010-2170 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.



Note: C2 and C3 should be placed as close to pins as possible.

| | TL1 | TL2 | TL3 |
|---|--------|--------|--------|
| Impedance | 50 Ohm | 50 Ohm | 50 Ohm |
| Physical Length | 0.04" | 0.04" | 0.04" |
| Electrical Length 5° 5° 5° | | | |
| PCB Material: 10 mil Rogers 4350, Er = 3.48 | | | |

| Recommended Component Values | |
|------------------------------|---------|
| C1 | 0.8 pF |
| C2 | 1 pF |
| C3 | 3.3 pF |
| C4 | 15 pF |
| C5 | 100 pF |
| C6 | 0.5 pF |
| C7 | 2.2 μF |
| L1 | 20 nH |
| L2 | 12 nH |
| R1 | 5.1 Ohm |

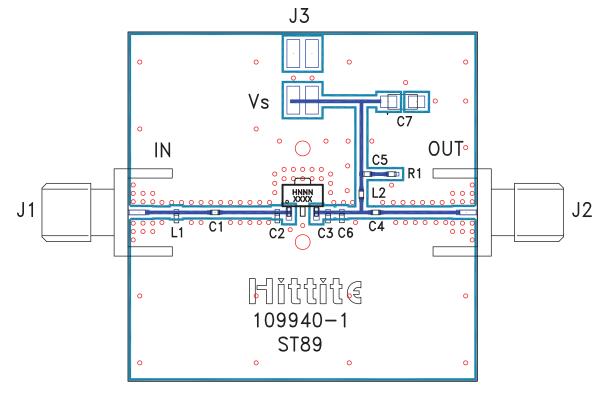
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InGaP HBT 1.6 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz



2100 MHz Evaluation PCB



List of Materials for Evaluation PCB 109942-2100 [1]

v02.0710

| Item | Description |
|--------------------|--|
| J1 - J2 | PCB Mount SMA Connector |
| J3 | 2 mm DC Header |
| C1 | 0.8 pF Capacitor, 0402 Pkg. |
| C2 | 1 pF Capacitor, 0402 Pkg. |
| C3 | 3.3 pF Capacitor, 0402 Pkg. |
| C4 | 15 pF Capacitor, 0402 Pkg. |
| C5 | 100 pF Capacitor, 0402 Pkg. |
| C6 | 0.5 pF Capacitor, 0402 Pkg. |
| C7 | 2.2 µF Capacitor, Tantalum |
| L1 | 20 nH Inductor, 0402 Pkg. |
| L2 | 12 nH Inductor, 0402 Pkg. |
| R1 | 5.1 Ohm Resistor, 0402 Pkg. |
| U1 | HMC453ST89 / HMC453ST89E Linear Amp |
| PCB ^[2] | 109940 Evaluation PCB, 10 mils |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350, Er = 3.48

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